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PTO/SB/17 (12-04v2)

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U.S. Patent and Trademark Office; U.S. DEPARTMENT OF COMMERCE

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Effective on 12/08/2004.
Fees pursuant to the Consolidated Appropriations Act, 2005 (H.R. 4818).**FEE TRANSMITTAL**
For FY 2005☐ Applicant claims small entity status. See 37 CFR 1.27**TOTAL AMOUNT OF PAYMENT** (\$) 100.00**Complete if Known**

Application Number	Patent#: 6,833,559
Filing Date	Issued: December 21, 2004
First Named Inventor	John T. Moore
Examiner Name	C. D. Wilson
Art Unit	2824
Attorney Docket No.	M4065.0693/P693-A

METHOD OF PAYMENT (check all that apply)

☐ Check ☒ Credit Card ☐ Money Order ☐ None ☐ Other (please identify): _____
☒ Deposit Account Deposit Account Number: 04-1073 Deposit Account Name: Dickstein Shapiro Morin & Oshinsky LLP

For the above-identified deposit account, the Director is hereby authorized to: (check all that apply)

☐ Charge fee(s) indicated below ☐ Charge fee(s) indicated below, except for the filing fee
☐ Charge any additional fee(s) or underpayment of fee(s) under 37 CFR 1.16 and 1.17 ☒ Credit any overpayments

FEE CALCULATION**1. BASIC FILING, SEARCH, AND EXAMINATION FEES**

Application Type	FILING FEES		SEARCH FEES		EXAMINATION FEES		Fees Paid (\$)
	Fee (\$)	Small Entity Fee (\$)	Fee (\$)	Small Entity Fee (\$)	Fee (\$)	Small Entity Fee (\$)	
Utility	300	150	500	250	200	100	
Design	200	100	100	50	130	65	
Plant	200	100	300	150	160	80	
Reissue	300	150	500	250	600	300	
Provisional	200	100	0	0	0	0	

2. EXCESS CLAIM FEES

Fee Description	Fee (\$)	Small Entity Fee (\$)
Each claim over 20 (including Reissues)	50	25
Each independent claim over 3 (including Reissues)	200	100
Multiple dependent claims	360	180

Total Claims - = Extra Claims x Fee (\$) = Fee Paid (\$)

Multiple Dependent Claims

Fee (\$) Fee Paid (\$)

Indep. Claims - = Extra Claims x Fee (\$) = Fee Paid (\$)

3. APPLICATION SIZE FEE

If the specification and drawings exceed 100 sheets of paper (excluding electronically filed sequence or computer listings under 37 CFR 1.52(e)), the application size fee due is \$250 (\$125 for small entity) for each additional 50 sheets or fraction thereof. See 35 U.S.C. 41(a)(1)(G) and 37 CFR 1.16(s).

Total Sheets - 100 = Extra Sheets /50 Number of each additional 50 or fraction thereof Fee (\$) Fee Paid (\$)

4. OTHER FEE(S)

Non-English Specification, \$130 fee (no small entity discount)

Other (e.g., late filing surcharge): 1811 Certificate of correction

Fees Paid (\$)

100.00

SUBMITTED BY

Signature		Registration No. (Attorney/Agent)	28,371	Telephone	(202) 828-2232
Name (Print/Type)	Thomas J. D'Amico	Date	August 19, 2005		

Certificate

AUG 24 2005

of Correction

08/22/2005 SSITHIB1 00000122 6833559

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100.00 OP

AUG 26 2005



Docket No.: M4065.0693/P693-A
(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Letters Patent of:
John T. Moore

Patent No.: 6,833,559 B2

Issued: December 21, 2004

For: Non-Volatile Resistance Variable Device

REQUEST FOR CERTIFICATE OF CORRECTION
PURSUANT TO 37 CFR 1.322 & 1.323

Commissioner for Patents
MS: Post Issue
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

Upon reviewing the above-identified patent, Patentee noted typographical errors which should be corrected.

In the References Cited under the "Other Publications":

The following contain typographical errors:

On page 4: El Bouchairi, B.; Bernede, J.C.; Burgaud, P., Propeties of
Ag_{2-x}Se_{1+x/n}-Si diodes, Thin Solid Films 110 (1983) 107-113.

"Propeties" should read -Properties--.

08/22/2005 SSITHIB1 00000122 6833559

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DSMDB.1967541.4

AUG 26 2005

On page 6: McHardy et al. *The dissolution of metals in amorphous chalcogenides and the effects of electron and ultraviolet radiation*, 20 J. Phys. C.: Solid State Phys., pp. 4055-4075. (1987)f. **"o" should read --of-- and "1987)f." should read --(1987).--;**

On page 6: Miyatani, S.-y., *Electrical properties of Ag₂Se*, J. Phys. Soc. Japan 13 (1958) 317. **"Electrical properties f" should read --Electrical properties of--;**

On page 6: Safran et al., *TEM study of Ag₂Se developed by the reaction of polycrystalline silver films and selenium*, 317 Thin Solid Films, pp. 72-76 (1998). **"study" should read --study-- and "selenium," should read --selenium,--.**

In the Specification:

Column 2, line 62, "an homogenous" should read --a homogenous--;

Column 3, line 45, "only, example such" should read --only, such--.

The grammatical errors in the specification, Col. 2, line 62 and Col. 3, line 45, were found in the application as-filed by the Patentee. The grammatical errors now sought to be corrected are inadvertent typographical errors, the correction of which does not involve new matter or require reexamination. Please charge our Credit Card in the amount of \$100.00 covering the fee set forth in 37 CFR 1.20(a). Credit Card Payment Form SB-2038, with a signature from an authorized cardholder, is enclosed.

The typographical errors in the References Cited under the "Other Publications" were not in the application as-filed or amended by the Patentee. These errors sought to be corrected are inadvertent typographical errors on the part of the USPTO; the correction of which does not involve new matter or require reexamination.

Transmitted herewith is a proposed Certificate of Correction effecting such amendment. Patentee respectfully solicits the granting of the requested Certificate of Correction.

The Commissioner is also hereby authorized to charge any deficiency in the fees filed, asserted to be filed or which should have been filed herewith (or with any paper hereafter filed in this application by this firm) to our Deposit Account No. 04-1073, under Order No. M4065.0693/P693-A. A duplicate copy of this paper is enclosed.

Dated: August 19, 2005

Respectfully submitted,

By 

Thomas J. D'Amico

Registration No.: 28,371

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UNITED STATES PATENT AND TRADEMARK OFFICE CERTIFICATE OF CORRECTION

PATENT NO. : 6,833,559 B2
DATED : December 21, 2004
INVENTOR : John T. Moore

It is certified that typographical errors appear in the above-identified patent and that said Letters Patent is hereby corrected by the addition of the information shown below:

In the References Cited under the "Other Publications":

The following contain typographical errors:

On page 4: El Bouchairi, B.; Bernede, J.C.; Burgaud, P., Propeties of $\text{Ag}_{2-x}\text{Se}_{1+x/n}\text{-Si}$ diodes, Thin Solid Films 110 (1983) 107-113. "Propeties" should read **Properties**.

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Column 3, line 45, "only, example such" should read **--only, such--**.

MAILING ADDRESS OF SENDER:

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PATENT NO. 6,833,559 B2